

Data Sheet December 1998 File Number 4624

# Radiation Hardened Dual JK Flip Flop

Harris' Satellite Applications Flow<sup>TM</sup> (SAF) devices are fully tested and guaranteed to 100kRAD total dose. These QML Class T devices are processed to a standard flow intended to meet the cost and shorter lead-time needs of large volume satellite manufacturers, while maintaining a high level of reliability.

The Harris HCTS109T is a Radiation Hardened Dual JK Flip Flop with set and reset. The flip flop changes state with the positive transition of the clock (CP1 or CP2).

## Specifications

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.

**Detailed Electrical Specifications for the HCTS109T are contained in SMD 5962-95769.** A "hot-link" is provided from our website for downloading.

http://www.semi.harris.com/families/smdrh.htm

Harris' Quality Management Plan (QM Plan), listing all Class T screening operations, is also available on our website. http://www.semi.harris.com/quality/manuals.htm

### Ordering Information

ORDERING NUMBER	PART NUMBER	TEMP. RANGE (°C)
5962R9576901TEC	HCTS109DTR	-55 to 125
HCTS109D/Sample	HCTS109D/Sample	25
5962R9576901TXC	HCTS109KTR	-55 to 125
HCTS109K/Sample	HCTS109K/Sample	25

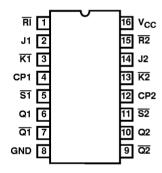
NOTE: *Minimum order quantity for -T is 1000 units*Orders must be placed through Harris Sales or Rep Offices.

### Features

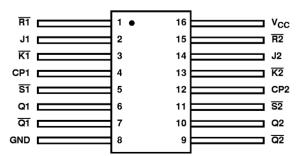
- QML Class T. Per MIL-PRF-38535
- · Radiation Performance
  - Gamma Dose (γ) 1 x 10<sup>5</sup> RAD(Si)
  - Latch-Up Free Under Any Conditions
  - SEP Effective LET No Upsets: >100 MEV-cm<sup>2</sup>/ma
  - Single Event Upset (SEU) Immunity < 2 x 10<sup>-9</sup> Errors/Bit-Day (Typ)
- · 3 Micron Radiation Hardened SOS CMOS
- · Significant Power Reduction Compared to LSTTL ICs
- DC Operating Voltage Range: 4.5V to 5.5V
- · LSTTL Input Logic Compatibility
  - $V_{II} = 0.8V Max$
  - $V_{IH} = V_{CC/2} Min$
- Input Current Levels li ≤ 5mA at V<sub>OI</sub>, V<sub>OH</sub>

### **Pinouts**

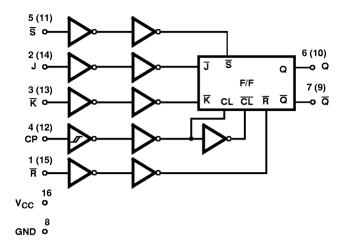
### HCTS109T (SBDIP), CDIP2-T16 TOP VIEW



# HCTS109T (FLATPACK), CDFP4-F16 TOP VIEW



# Functional Diagram



### TRUTH TABLE

INPUTS			OUTPUTS			
S	R	СР	J	ĸ	Q	Q
L	Н	Х	Х	Х	Н	L
Н	L	Х	Х	Х	L	Н
L	L	Х	Х	Х	Η÷	Ηţ
Н	Н		L	L	L	Н
Н	Н		Н	L	Toggle	
Н	Н		L	Н	No Change	
Н	Н		Н	Н	Н	L
Н	Н	L	Х	Х	No Change	

 $<sup>\</sup>dagger$  Unpredictable and unstable condition if both  $\overline{S}$  and  $\overline{R}$  go high simultaneously.

### Die Characteristics

**DIE DIMENSIONS:** 

 $2261\mu m \times 2235\mu m \times 533\mu m \pm 51\mu m$ )

89 x 88 x 21mils ±2mil

**METALLIZATION:** 

Type: Al Si

Thickness: 11kÅ 1kÅ

**SUBSTRATE POTENTIAL:** 

Unbiased Silicon on Sapphire

**BACKSIDE FINISH:** 

Sapphire

PASSIVATION:

Type: Silox (SiO<sub>2</sub>)

Thickness: 13kÅ ±2.6kÅ

WORST CASE CURRENT DENSITY:

< 2.0e5 A/cm<sup>2</sup>

TRANSISTOR COUNT:

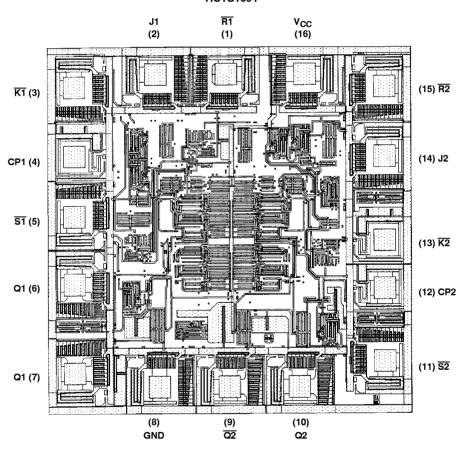
268

PROCESS:

CMOS SOS

## Metallization Mask Layout

#### HCTS109T



NOTE: The die diagram is a generic plot form a similar HCS device. It is intended to indicate approximate die size and bond pad location. The mask series for the HCTS109 is TA14440A.

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